

Low-Cost, 1.27W Audio Power Amplifiers

■ General Description

The LN4872 is a Class-AB audio power amplifier designed for mobile phones and other portable communication devices. It is capable of delivering 1.2W of continuous average power to an 8Ω BTL load with less than 1% distortion (THD+N) from a 5V DC power supply.

The LN4872 was designed specifically to provide high quality output power with a minimal amount of external components. It does not require output coupling capacitors or bootstrap capacitors. And with ultra low shutdown current, the LN4872 is ideally suited for mobile phone and other low voltage applications where minimal power consumption is a primary requirement. With special pop-click eliminating circuit, the LN4872 provides perfect pop-click characteristic during turn-on and turn-off transitions.

The LN4872 is unity-gain stable and can be configured by external gain-setting resistors.

■ Key Specifications

- PSRR @ $f_{IN}=217\text{Hz}$ VDD = 5V 62dB(typ.)
- Power Output @ VDD=5V & 1% THD RL=8Ω
1.27W(typ.)
- Power Output @ VDD=3V &1% THD RL=8Ω
400mW(typ.)
- Power Output @ VDD=5V &1% THD RL=4Ω
2W(typ.)
- Shutdown Current 0.1μA(typ.)

■ Ordering Information

Ordering Number	Package Type
LN4872M	SOP-8
LN4872MM	MSOP-8

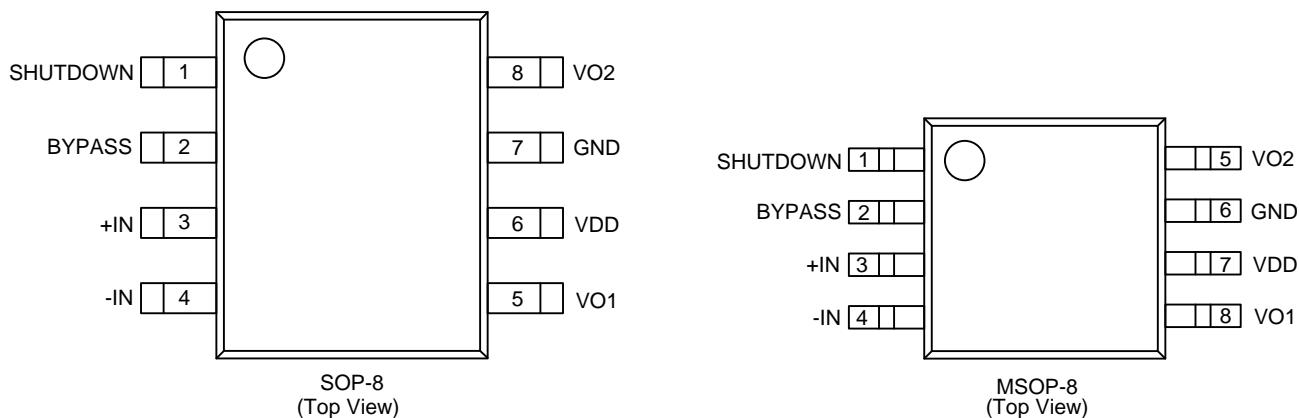
■ Operating Ratings

Temperature Range

TMIN ≤ TA ≤ TMAX ----- -40°C ≤ TA ≤ 85°C

Supply Voltage ----- 2.2V ≤ VDD ≤ 5.5V

■ Pin Configuration



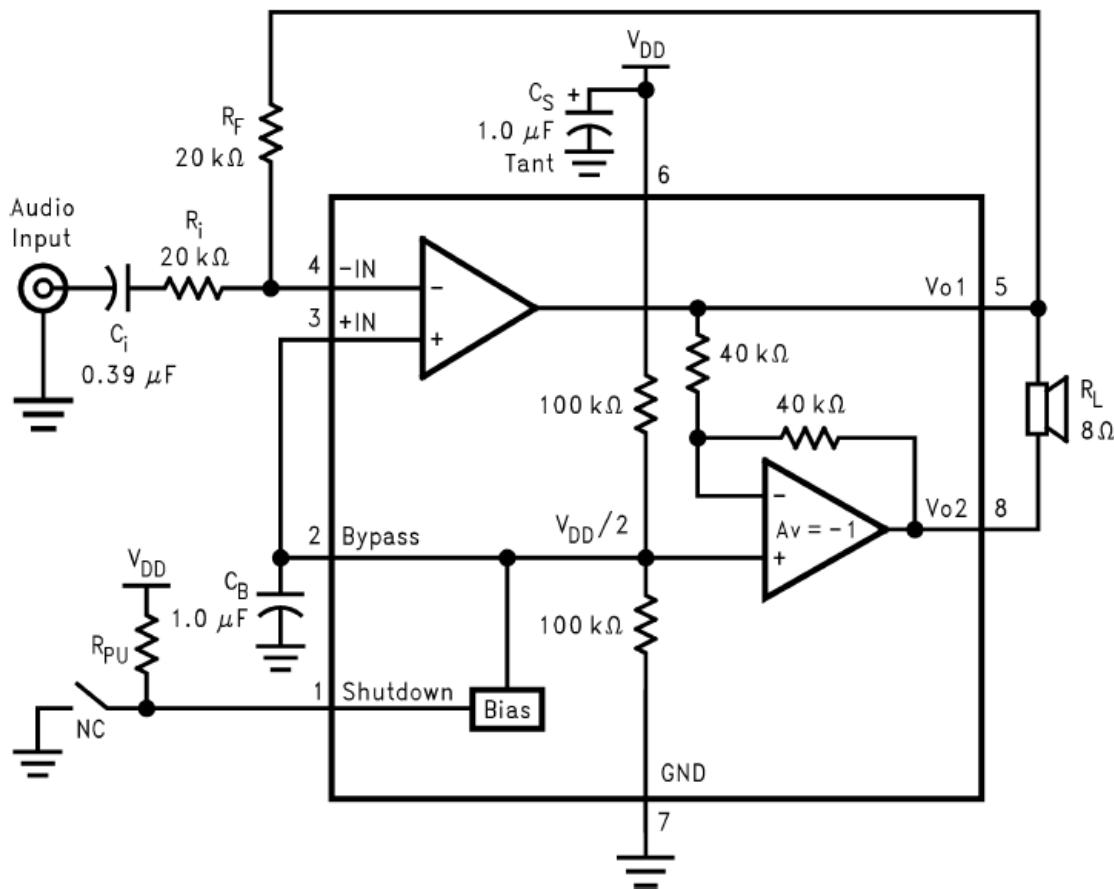
Ordering Number: LN4872M

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■ Pin Function Description

Pin Name	Pin Number	I/O	Function Description
SHUTDOWN	1	I	Shutdown terminal (active high logic)
BYPASS	2		Adding a bypass capacitor
+IN	3	I	Channel positive input
-IN	4	I	Channel negative input
VO1	5	O	Channel output 1
VDD	6		Power supply
GND	7		High-current ground
VO2	8	O	Channel output 2

■ Function Block Diagram



■ Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Supply Voltage	V_{DD}	-0.3—6.5	V
Input Voltage	V_{IN}	-0.3— $V_{DD}+0.3$	V
Power Output	—	Internal limit	
Junction Temperature	—	-150	°C
Storage Temperature	T_{stg}	-65—150	°C
ESD Susceptibility	-	8000	V

■ Electrical Characteristics

(VDD = 5V Unless otherwise specified. Limits apply for TA = 25°C.)

Symbol	Parameters	Test Conditions	Min.	Typ.	Max.	Unit
I_{DD}	Quiescent Power Supply Current	VIN = 0V, $I_o = 0A$, No Load	—	4	8	mA
		VIN = 0V, $I_o = 0A$, 8Ω Load	—	5	10	mA
I_{SD}	Shutdown Current	$V_{SHUTDOWN} = 0V$	—	0.1	2	μA
V_{SDIH}	Shutdown Voltage Input High		1.2	—	—	V
V_{SDIL}	Shutdown Voltage Input Low		—	—	0.4	V
V_{os}	Output Offset Voltage		—	7	50	mV
$R_{OUT-GND}$	Resistor Output to GND		7.0	8.5	9.7	kΩ
P_o	Output Power (8Ω)	THD = 1% (max); $f = 1\text{ kHz}$ 8Ω Load	0.8	1.2	—	W
T_{wu}	Wake-up time		—	170	220	ms
T_{SD}	Thermal Shutdown Temperature		150	170	190	°C
THD+N	Total Harmonic Distortion+Noise	$P_o = 0.4\text{ W rms}; f = 1\text{ kHz}$	—	0.1	—	%
PSRR	Power Supply Rejection Ratio	$V_{ripple} = 200\text{ mV}_{\text{sine p-p}}$ $f = 217\text{ Hz}$	55	62	—	dB
		$V_{ripple} = 200\text{ mV}_{\text{sine p-p}}$ $f = 1\text{ kHz}$		66	—	
T_{SDT}	Shut Down Time	8Ω Load	—	1.0	—	ms

(VDD = 3V Unless otherwise specified. Limits apply for TA = 25°C.)

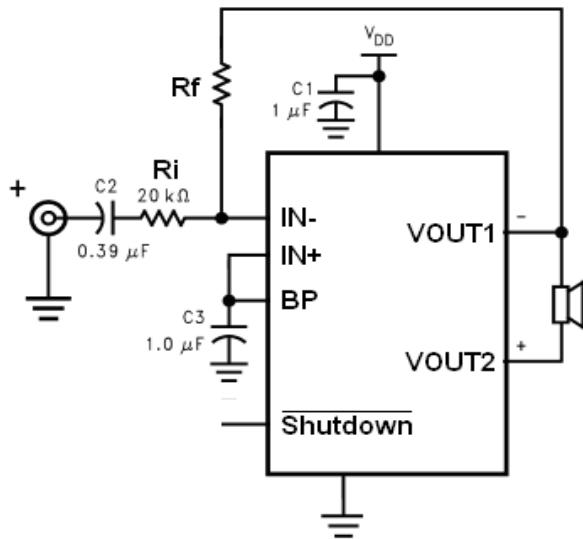
Symbol	Parameters	Test Conditions	Min.	Typ.	Max.	Unit
I_{DD}	Quiescent Power	VIN = 0V, $I_o = 0A$, No Load	—	3.5	7	mA
	Supply Current	VIN = 0V, $I_o = 0A$, 8Ω Load	—	4.5	9	mA
I_{SD}	Shutdown Current	$V_{SHUTDOWN} = 0V$	—	0.1	2	μA
V_{SDIH}	Shutdown Voltage Input High		1.2	—	—	V
V_{SDIL}	Shutdown Voltage Input Low		—	—	0.4	V
V_{os}	Output Offset Voltage		—	7	50	mV
$R_{OUT-GND}$	Resistor Output to GND		7.0	8.5	9.7	kΩ
P_o	Output Power (8Ω)	THD = 2% (max); $f = 1\text{ kHz}$ 8Ω Load	0.28	0.41	—	W
T_{WU}	Wake-up time		—	170	220	ms
T_{SD}	Thermal Shutdown Temperature		150	170	190	°C
THD+N	Total Harmonic Distortion+Noise	$P_o = 0.4\text{ W rms}; f = 1\text{ kHz}$	—	0.1	—	%
PSRR	Power Supply Rejection Ratio	$V_{ripple} = 200\text{ mV}_{\text{sine p-p}}$ $f = 217\text{ Hz}$	45	56	—	dB
		$V_{ripple} = 200\text{ mV}_{\text{sine p-p}}$ $f = 1\text{ kHz}$		62	—	

(VDD = 2.6V Unless otherwise specified. Limits apply for TA = 25°C.)

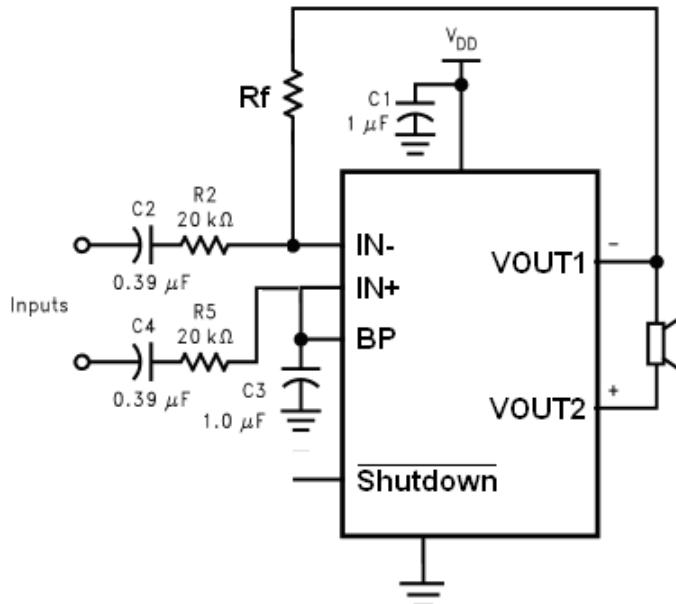
Symbol	Parameters	Test Conditions	Min.	Typ.	Max.	Unit
I_{DD}	Quiescent Power Supply Current	VIN = 0V, $I_o = 0A$, No Load	—	2.6	5.5	mA
I_{SD}		$V_{SHUTDOWN} = 0V$	—	0.1	2	μA
P_o	Output Power	THD = 1% (max); $f = 1\text{ kHz}$		0.3	—	W
				0.5	—	
THD+N	Total Harmonic Distortion+Noise	$P_o = 0.1\text{ W rms}; f = 1\text{ kHz}$	—	0.08	—	%
PSRR	Power Supply Rejection Ratio	$V_{ripple} = 200\text{ mV}_{\text{sine p-p}}$ $f = 217\text{ Hz}$	—	44	—	dB
		$V_{ripple} = 200\text{ mV}_{\text{sine p-p}}$ $f = 1\text{ kHz}$		44	—	

■ Typical Application Circuit

- Single-Ended Input Configuration



- Differential Input Configuration

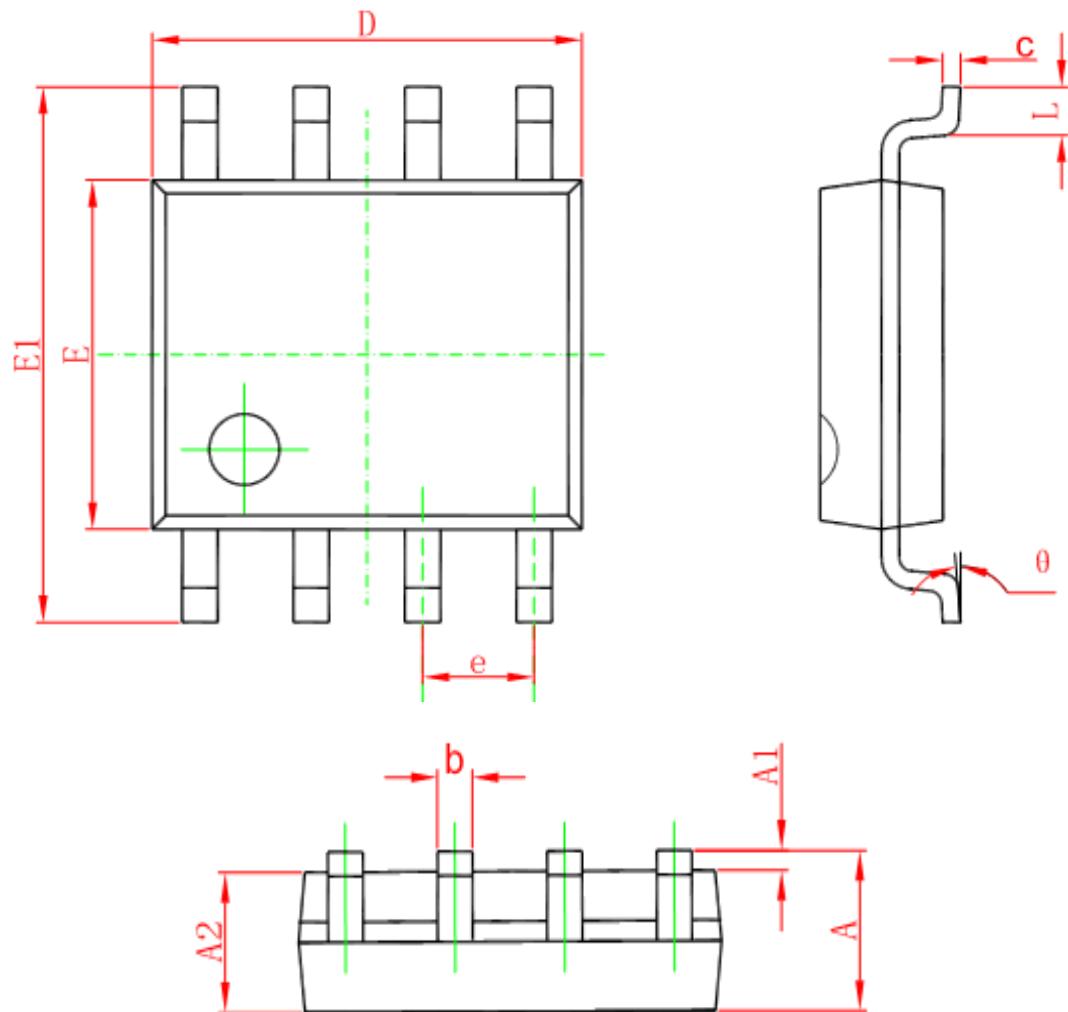


The resistors (Rf) set the gain of the amplifier according to equation (1). Gain = $2 * R_f / R_i$

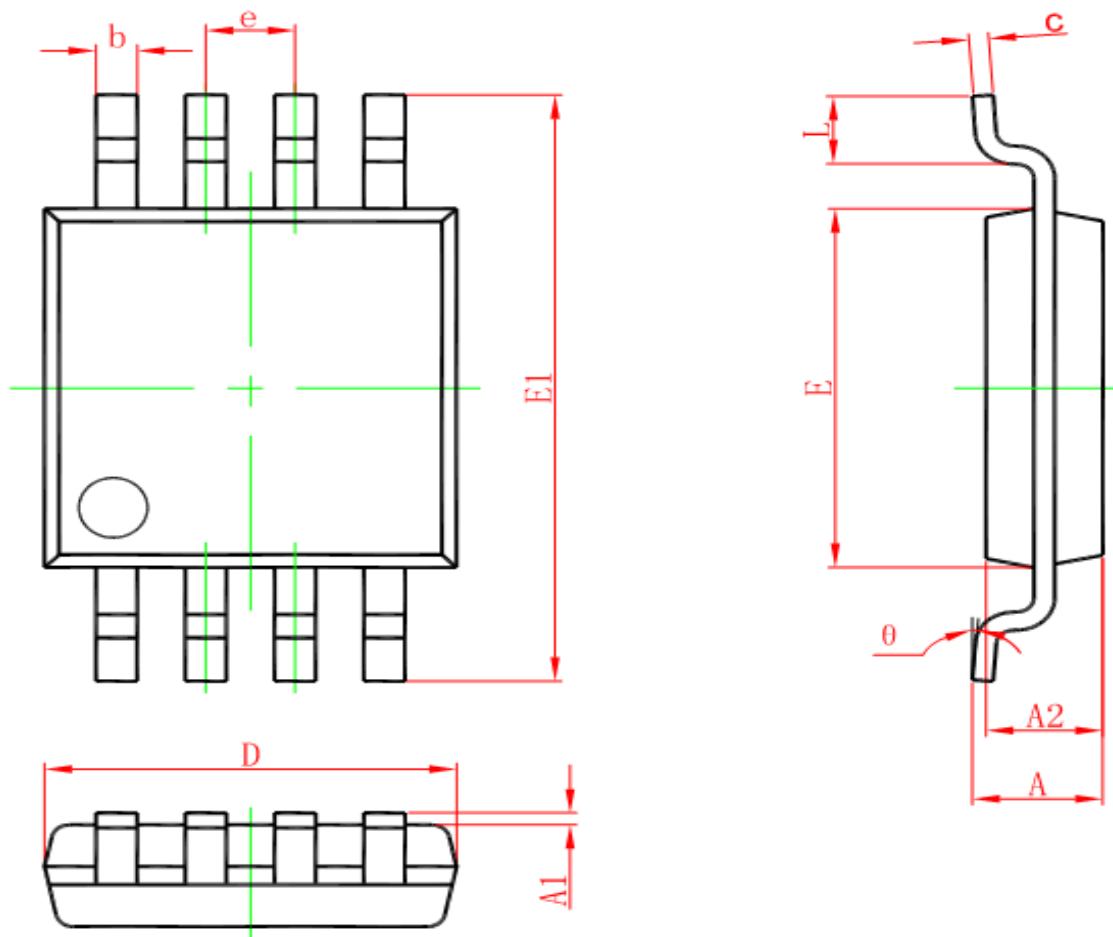
Typical $R_i=20K$ $R_f=20K$, GAIN=2

■ Package Information

- SOP-8



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.330	0.510	0.013	0.020
c	0.170	0.250	0.006	0.010
D	4.700	5.100	0.185	0.200
E	3.800	4.000	0.150	0.157
E1	5.800	6.200	0.228	0.244
e	1.270 (BSC)		0.050 (BSC)	
L	0.400	1.270	0.016	0.050
θ	0°	8°	0°	8°



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.820	1.100	0.032	0.043
A1	0.020	0.150	0.001	0.006
A2	0.750	0.950	0.030	0.037
b	0.250	0.380	0.010	0.015
c	0.090	0.230	0.004	0.009
D	2.900	3.100	0.114	0.122
e	0.650(BSC)		0.026(BSC)	
E	2.900	3.100	0.114	0.122
E1	4.750	5.050	0.187	0.199
L	0.400	0.800	0.016	0.031
θ	0°	6°	0°	6°